CNZ2153 (ON2153)

Reflective Photosensor

For contactless SW and object detection

Overview

CNZ2153 is a photosensor detecting the change of reflective light in which a high efficiency GaAs infrared light emitting diode is used as the light emitting element, and a Si phototransistor is used as the light detecting element. The two elements are located parallel in the same direction and objects are detected when passing in front of the device.

Features

- Fast response
- Small size, light weight

Applications

- Detection of paper, film and cloth
- Optical mark reading
- Detection of coin and bill
- Detection of position and edge
- Start, end mark detection of magnetic tape

Absolute Maximum Ratings $T_a = 25^{\circ}C$

F	Symbol	Rating	Unit	
Input (Light emitting diode)	Power dissipation *1	P _D	75	mW
	Forward current	$I_{\rm F}$	50	mA
	Reverse voltage	V _R	3	V
Output (Photo transistor)	Collector-emitter voltage (Base open)	V _{CEO} 30		V
	Emitter-collector voltage (Base open)	V _{ECO}	5	V
	Collector current	I _C	20	mA
	Collector power dissipation *2	P _C	50	mW
Operating ambient temp	T _{opr}	-25 to +85	°C	
Storage temperature	T _{stg}	-30 to +100	°C	

Note) *1: Input power derating ratio is 1.0 mW/°C at $T_a \ge 25^{\circ}C$

*2: Output power derating ratio is 0.67 mW/°C at $T_a \ge 25^{\circ}C$

Note) The part number in the parenthesis shows conventional part number.

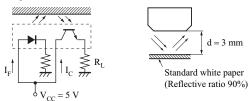
Electrical-Optical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

	Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Input characteristics	Reverse current	I _R	$V_R = 3 V$			10	μΑ
	Forward voltage	V _F	$I_F = 50 \text{ mA}$		1.2	1.5	V
	Terminal capacitance	Ct	$V_{\rm R} = 0 V, f = 1 MHz$		50		pF
Output characteristics	Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{CE} = 10 V$			0.2	μΑ
Transfer characteristics	Collector current *1, *2	I _C	$V_{CC} = 5 \text{ V}, I_F = 20 \text{ mA},$ $R_L = 100 \Omega$	100		1 200	μΑ
	Collector-emitter saturation voltage	V _{CE(sat)}	$I_{\rm F} = 50 \text{ mA}, I_{\rm C} = 0.1 \text{ mA}$			0.5	V
	Rise time *3	t _r	$V_{\rm CC} = 10 \text{ V}, I_{\rm C} = 0.1 \text{ mA},$		6.0		μs
	Fall time *3	t _f	$R_{\rm L} = 100 \Omega$		6.0		μs

Note) 1. Input and output are practiced by electricity.

2. This device is designed by disregarding radiation.

3. *1: Output current measurement circuit

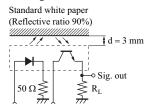


*2: Rank classification

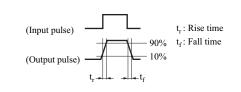
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Rank	Q	R	S	No-rank
I _C (μA)	100 to 300	200 to 600	400 to 1 200	100 to 1200

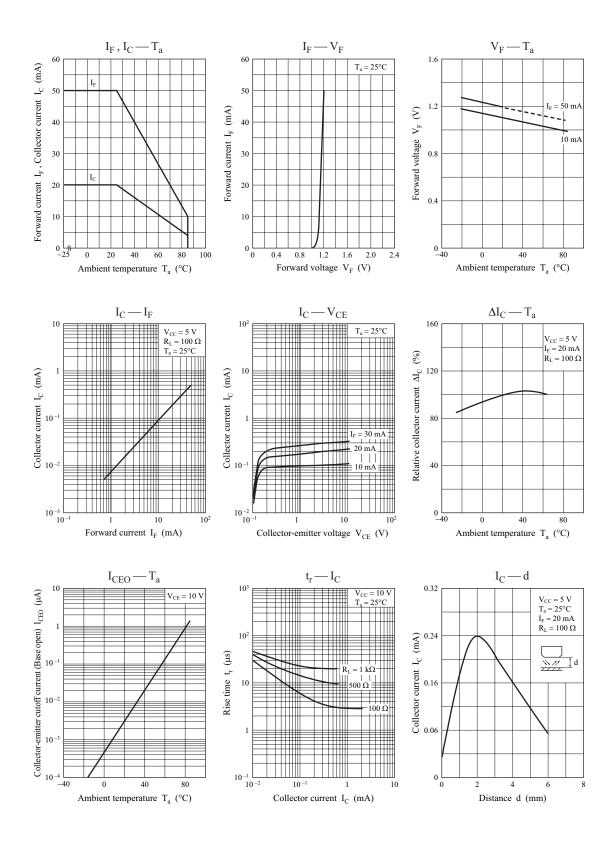
*3: Switching time measurement circuit



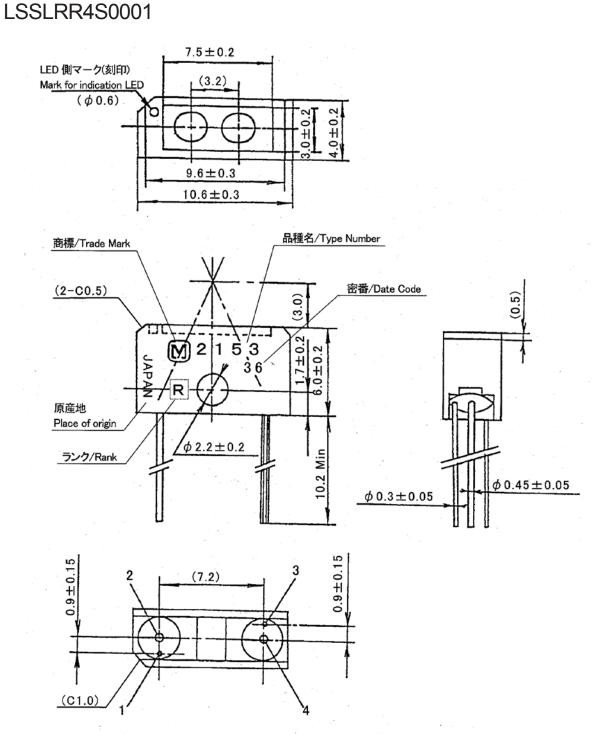
 V_{CC}



Panasonic



Package (Unit: mm)



(注 1) 密番及びマークは、目視又は顕微鏡に於いて解読できる事。 (Note1) What a date code and mark sees an attention and can decode in a microscope.

• Pin name

- 1: Cathode
- 2: Anode
- 3: Emitter
- 4: Collector

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